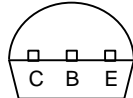


Features

- Through Hole Package
- Capable of 600mWatts of Power Dissipation

Pin Configuration
Bottom View



NPN General Purpose Amplifier

Electrical Characteristics @ 25°C Unless Otherwise Specified

Symbol	Parameter	Min	Max	Units
OFF CHARACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage* ($I_C=1.0\text{mA}$, $I_B=0$)	40		Vdc
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage ($I_C=10\mu\text{A}$, $I_E=0$)	60		Vdc
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage ($I_E=10\mu\text{A}$, $I_C=0$)	6.0		Vdc
I_{BL}	Base Cutoff Current ($V_{CE}=30\text{Vdc}$, $V_{BE}=3.0\text{Vdc}$)		50	nAdc
I_{CEX}	Collector Cutoff Current ($V_{CE}=30\text{Vdc}$, $V_{BE}=3.0\text{Vdc}$)		50	nAdc

ON CHARACTERISTICS

h_{FE}	DC Current Gain* ($I_C=0.1\text{mA}$, $V_{CE}=1.0\text{Vdc}$) ($I_C=1.0\text{mA}$, $V_{CE}=1.0\text{Vdc}$) ($I_C=10\text{mA}$, $V_{CE}=1.0\text{Vdc}$) ($I_C=50\text{mA}$, $V_{CE}=1.0\text{Vdc}$) ($I_C=100\text{mA}$, $V_{CE}=1.0\text{Vdc}$)	40 70 100 60 30	300	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ($I_C=10\text{mA}$, $I_B=1.0\text{mA}$) ($I_C=50\text{mA}$, $I_B=5.0\text{mA}$)		0.2 0.4	Vdc
$V_{BE(sat)}$	Base-Emitter Saturation Voltage ($I_C=10\text{mA}$, $I_B=1.0\text{mA}$) ($I_C=50\text{mA}$, $I_B=5.0\text{mA}$)	0.65	0.85 0.95	Vdc

SMALL-SIGNAL CHARACTERISTICS

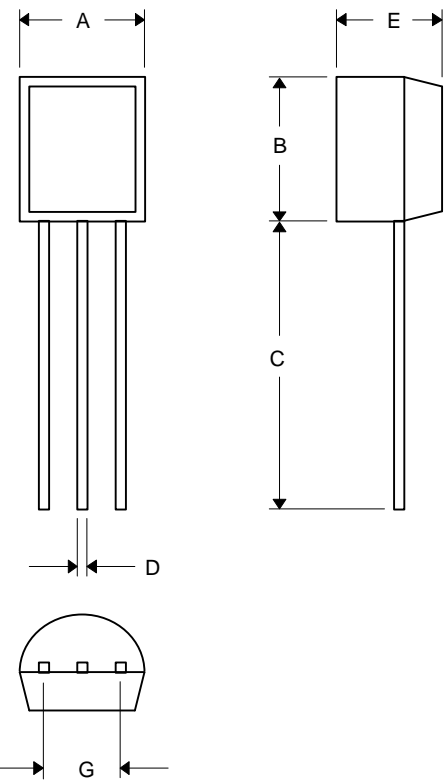
f_T	Current Gain-Bandwidth Product ($I_C=10\text{mA}$, $V_{CE}=20\text{Vdc}$, $f=100\text{MHz}$)	250		MHz
C_{obo}	Output Capacitance ($V_{CB}=5.0\text{Vdc}$, $I_E=0$, $f=1.0\text{MHz}$)		4.0	pF
C_{ibo}	Input Capacitance ($V_{BE}=0.5\text{Vdc}$, $I_C=0$, $f=1.0\text{MHz}$)		8.0	pF
NF	Noise Figure ($I_C=100\mu\text{A}$, $V_{CE}=5.0\text{Vdc}$, $R_S=1.0\text{k}\Omega$, $f=10\text{Hz}$ to 15.7kHz)		5.0	dB

SWITCHING CHARACTERISTICS

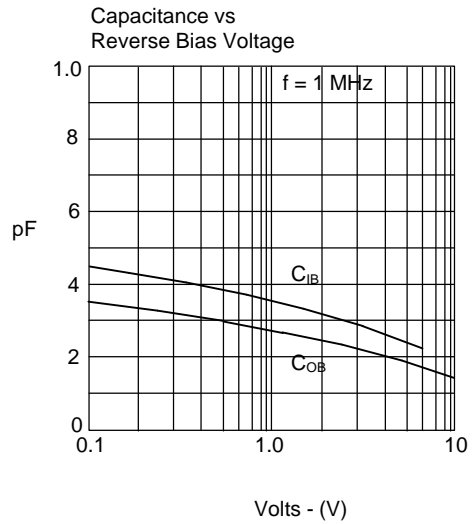
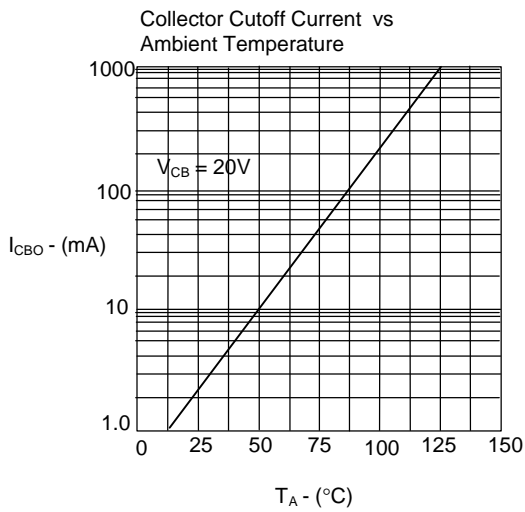
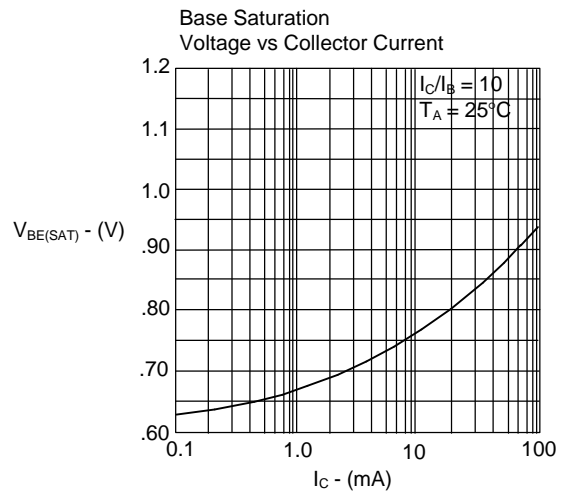
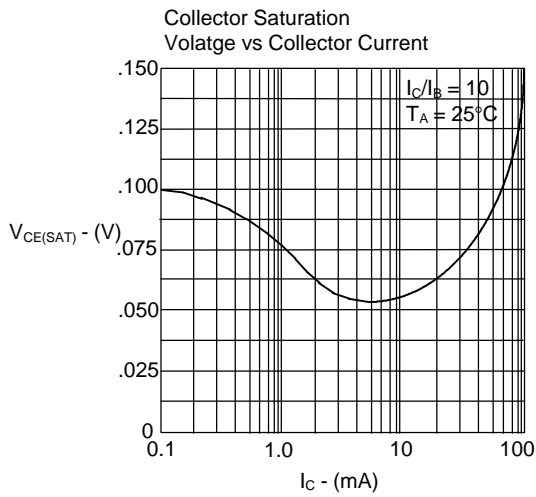
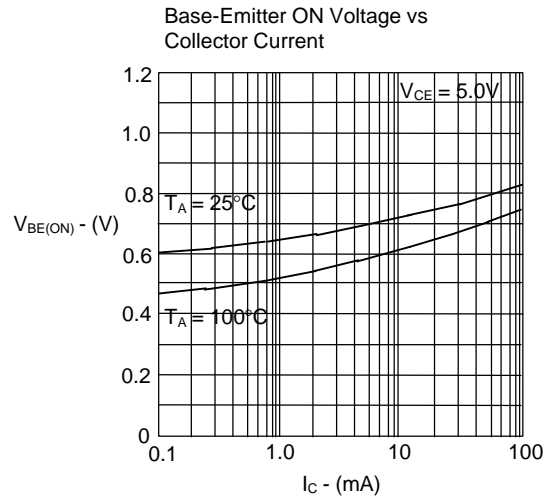
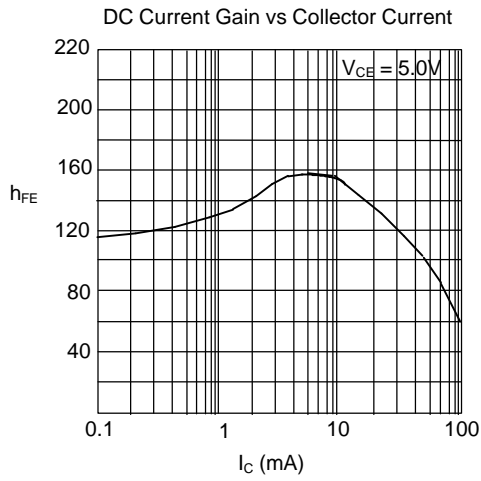
t_d	Delay Time	($V_{CC}=3.0\text{Vdc}$, $V_{BE}=0.5\text{Vdc}$)	35	ns
t_r	Rise Time	$I_C=10\text{mA}$, $I_{B1}=1.0\text{mA}$	35	ns
t_s	Storage Time	($V_{CC}=3.0\text{Vdc}$, $I_C=10\text{mA}$)	200	ns
t_f	Fall Time	$I_{B1}=I_{B2}=1.0\text{mA}$	50	ns

*Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2.0\%$

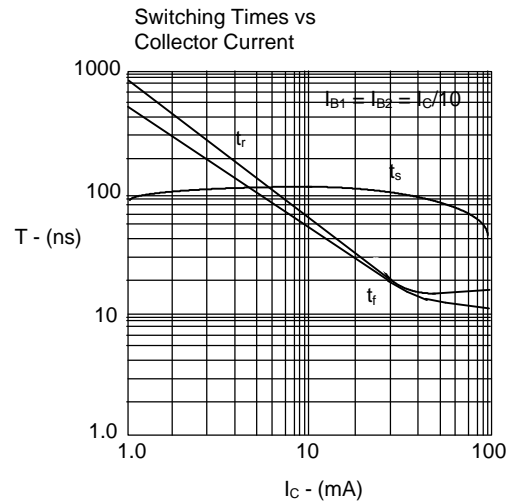
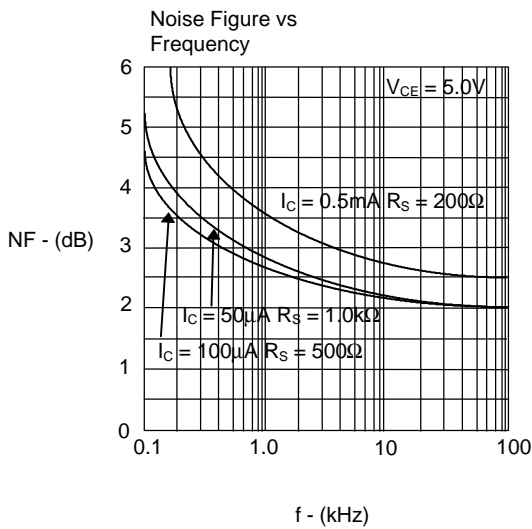
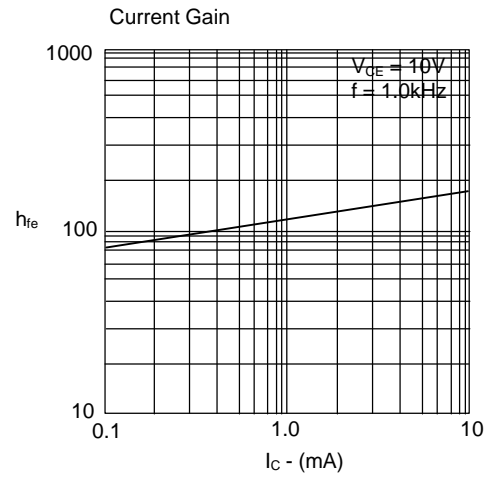
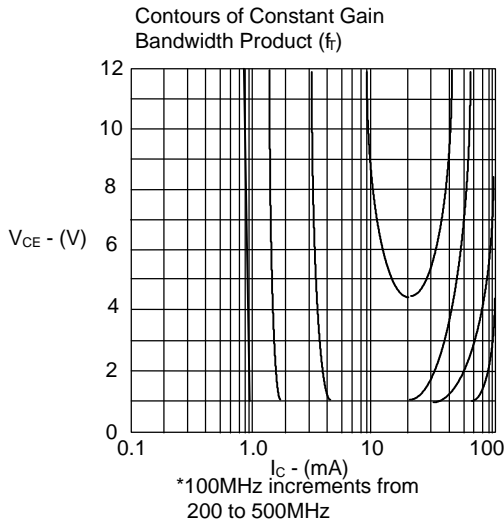
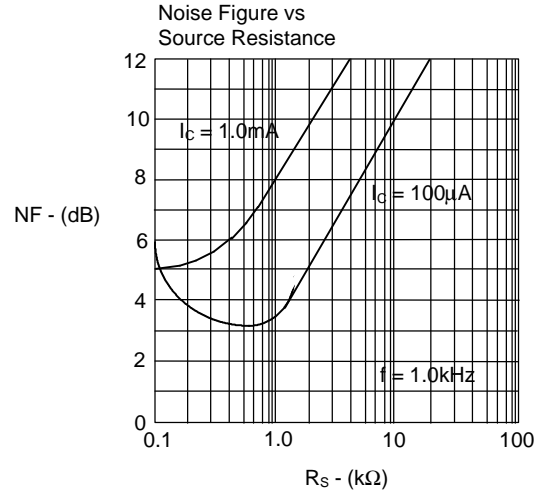
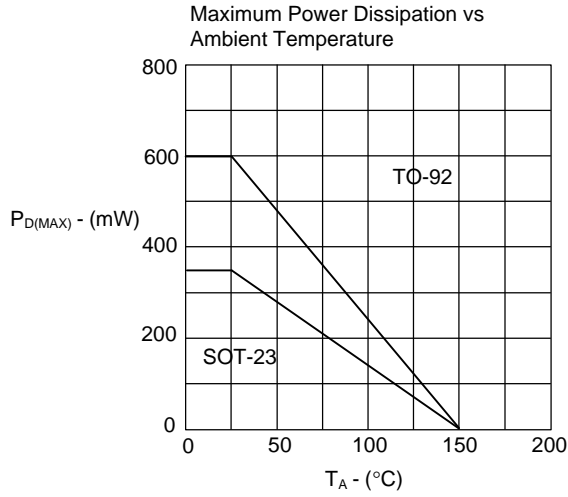
TO-92



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.170	.190	4.33	4.83	
B	.170	.190	4.30	4.83	
C	.550	.590	13.97	14.97	
D	.010	.020	0.36	0.56	
E	.130	.160	3.30	3.96	
G	.010	.104	2.44	2.64	



2N3904



2N3904

